



## SSCN2222AGS6

### High Frequency High Gain NPN Power BJT

#### ➤ Features

VCB	VCE	VEB	IC
75V	40V	6V	600mA

#### ➤ Description

This product is general usage and suitable for many different applications. It can be used for medium power amplifiers and switches requiring collector currents up to 500 mA.

#### ➤ Applications

- Low current and high precision circuits such preamplifiers, oscillators, current mirror configuration
- Medium power amplification and switching

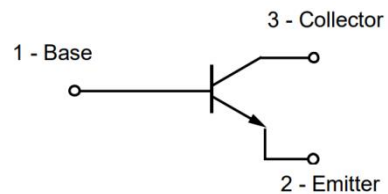
#### ➤ Ordering Information

Device	Package	Shipping
SSCN2222AGS6	SOT-23	3000/Reel

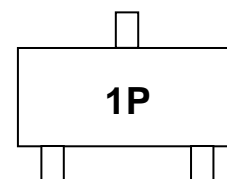
#### ➤ Pin configuration



**SOT-23**



**Circuit Diagram**



**Marking(Top View)**



➤ **Absolute Maximum Ratings**( $T_A=25^{\circ}\text{C}$  unless otherwise noted)

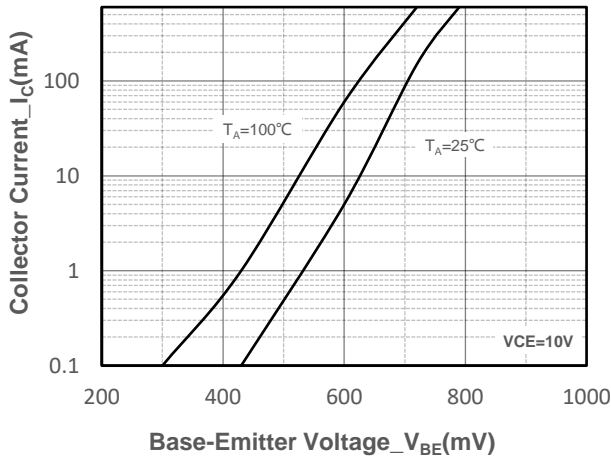
Parameter	Symbol	Value	Unit
Collector-Base Voltage	$V_{CB0}$	75	V
Collector- Emitter Voltage	$V_{CEO}$	40	V
Emitter-Base Voltage	$V_{EBO}$	6	V
Collector Current-Continuous	$I_C$	600	mA
Collector Power Dissipation	$P_C$	225	mW
Junction Temperature	$T_J$	150	$^{\circ}\text{C}$
Storage Temperature	$T_{STG}$	-55 to 150	$^{\circ}\text{C}$

➤ **Electrical Characteristics** ( $T_A=25^{\circ}\text{C}$  unless otherwise noted)

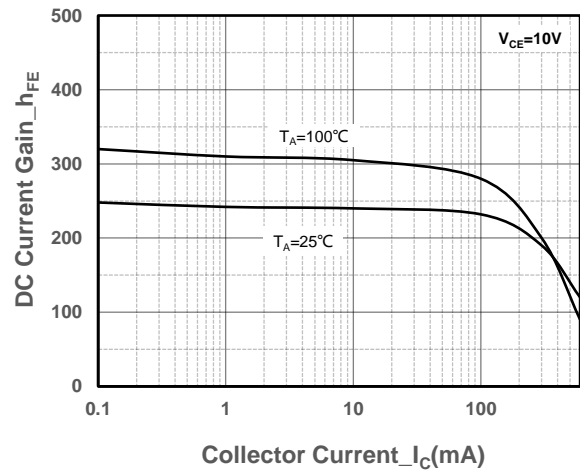
Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Collector-Base Breakdown Voltage	$BV_{CB0}$	$I_C=0.1\text{mA}, I_E=0$	75			V
Collector-emitter Breakdown Voltage	$BV_{CEO}$	$I_C=1\text{mA}, I_B=0$	40			V
Emitter -Base Breakdown Voltage	$BV_{EBO}$	$I_E=0.1\text{mA}, I_C=0$	6			V
Collector Cutoff Current	$I_{CBO}$	$V_{CB}=60\text{V}, I_E=0$			0.01	$\mu\text{A}$
Collector Cutoff Current	$I_{CEX}$	$V_{CE}=60\text{V}, V_{BE}=3\text{V}$			0.01	$\mu\text{A}$
Emitter Cutoff Current	$I_{EBO}$	$V_{EB}=3\text{V}, I_C=0$			0.01	$\mu\text{A}$
DC Current Gain	$h_{FE1}$	$V_{CE}=10\text{V}, I_C=150\text{mA}$	100		300	
	$h_{FE2}$	$V_{CE}=10\text{V}, I_C=0.1\text{mA}$	40			
	$h_{FE3}$	$V_{CE}=10\text{V}, I_C=500\text{mA}$	40			
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=500\text{mA}, I_B=50\text{mA}$			1.0	V
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=500\text{mA}, I_B=50\text{mA}$			2.0	V
Transition frequency	$f_T$	$V_{CE}=20\text{V}, I_C=20\text{mA}$ $f=100\text{MHz}$	250			MHz
Delay Time	$t_d$	$V_{CC}=30\text{V}, I_C=150\text{mA},$ $I_{B1}=15\text{mA}$			10	ns
Rise Time	$t_r$	$V_{CC}=30\text{V}, I_C=150\text{mA},$ $I_{B1}=15\text{mA}$			25	ns
Storage Time	$t_s$	$V_{CC}=30\text{V}, I_C=150\text{mA},$ $I_{B1}= I_{B2}=15\text{mA}$			225	ns
Fall Time	$t_f$	$V_{CC}=30\text{V}, I_C=150\text{mA},$ $I_{B1}= I_{B2}=15\text{mA}$			60	ns



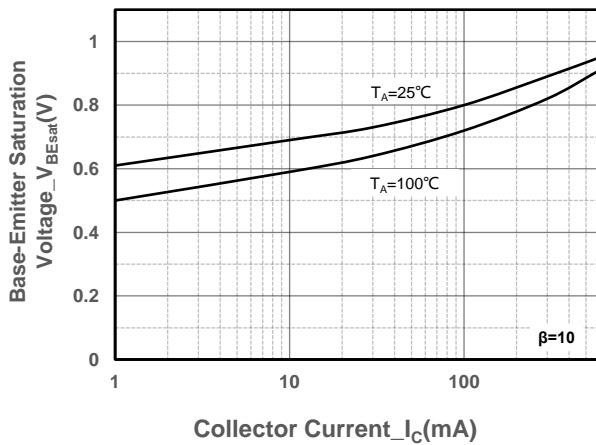
## ➤ Typical Performance Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)



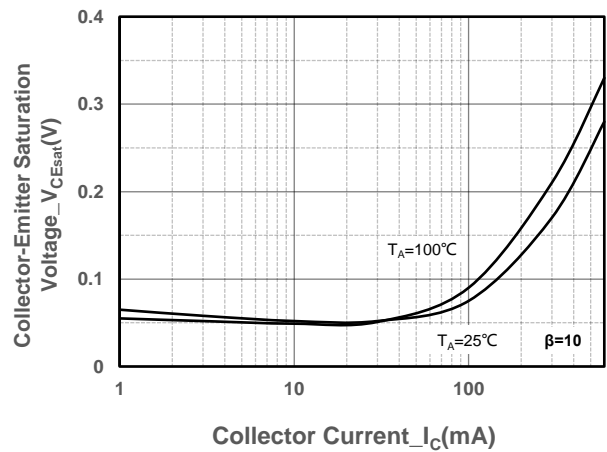
Collector Current vs. Base-Emitter Voltage



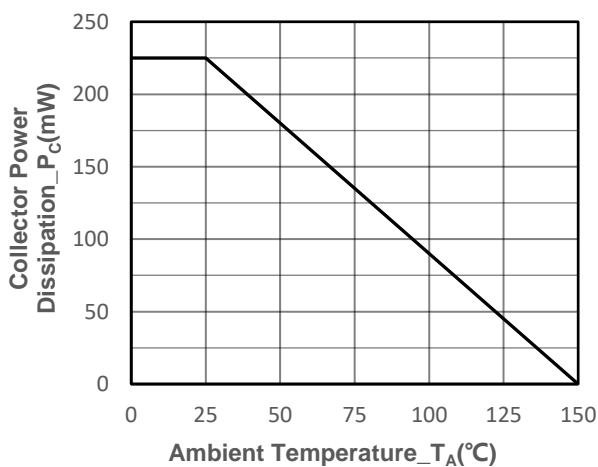
DC Current Gain vs. Collector Current



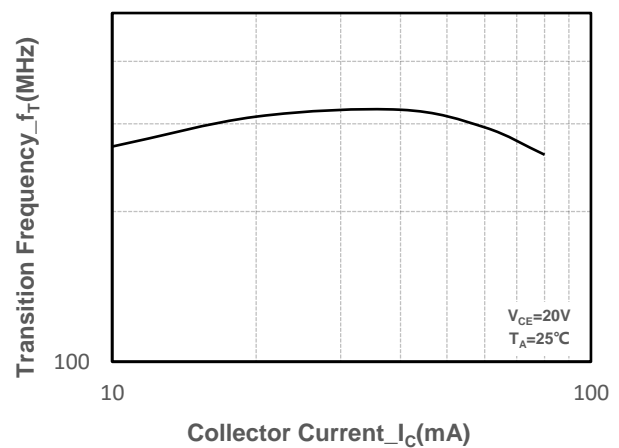
$V_{BE(sat)}$  vs. Collector Current



$V_{CE(sat)}$  vs. Collector Current



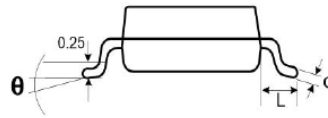
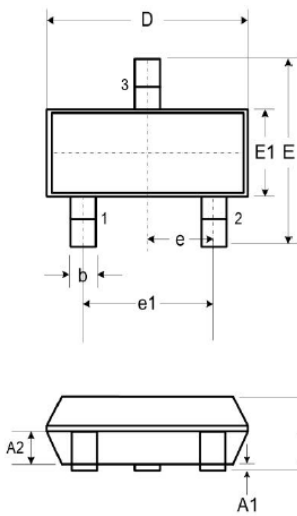
Power derating vs. Ambient temperature



Transition Frequency vs. Collector Current

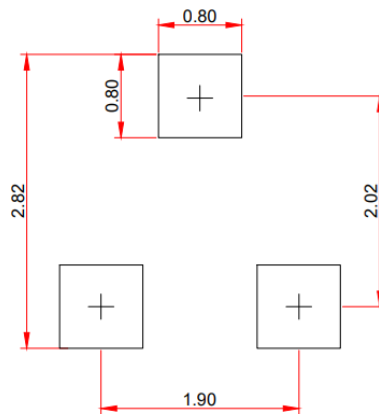


## ● Package Information



DIM	Millimeters		
	Min.	Typ.	Max.
A	0.89	-	1.12
A1	0.01	-	0.10
A2	0.88	0.95	1.02
b	0.30	-	0.51
c	0.08	-	0.18
D	2.80	2.90	3.04
E	2.10	2.37	2.64
E1	1.20	1.30	1.40
e	0.95		
e1	1.90		
L	0.40	0.50	0.60
L1	0.55		
N	3		
θ	0°	-	8°

## Recommended Pad outline(Unit: mm)





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